



Description

The RJK0396DPA-00#J53 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 30V$ $I_D = 50A$

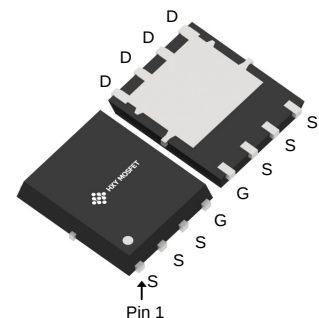
$R_{DS(ON)} < 8.5m\Omega$ $V_{GS}=10V$

Application

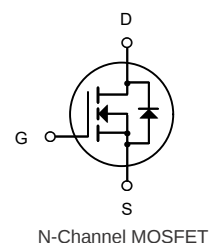
Battery protection

Load switch

Uninterruptible power supply



DFN5X6-8L



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
RJK0396DPA-00#J53	DFN5X6-8L	HXY MOSFET	5000

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D@T_C=25^{\circ}C$	Continuous Drain Current, V_{GS} @ 10V	60	A
$I_D@T_C=100^{\circ}C$	Continuous Drain Current, V_{GS} @ 10V	38	A
I_{DM}	Pulsed Drain Current ¹	200	A
EAS	Single Pulse Avalanche Energy ²	36	mJ
I_{AS}	Avalanche Current	50	A
$P_D@T_C=25^{\circ}C$	Total Power Dissipation ⁴	31	W
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range	-55 to 150	°C
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	62	°C/W
$R_{\theta JC}$	Thermal Resistance Junction-Case ³	27	°C/W



Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	30	---	---	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} =0V, V _{DS} =24V	---	---	1	μA
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V, V _{DS} =0A	---	---	±100	nA
V _{GS(th)}	GATE-Source Threshold Voltage	V _{GS} =V _{DS} , I _D =250μA	1.2	1.5	2.5	V
R _{DS(ON)}	Drain-Source On Resistance ⁴	V _{GS} =10V, I _D =30A	---	6.5	8.5	mΩ
		V _{GS} =4.5V, I _D =15A	---	11	14	
G _{FS}	Forward Transconductance	V _{DS} =5V, I _D =30A	---	38	---	S
C _{iss}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1MHz	---	1317	1844	pF
C _{oss}	Output Capacitance		---	163	228	
C _{rss}	Reverse Transfer Capacitance		---	131	183	
t _{d(on)}	Turn-On Delay Time	V _{DD} =15V, I _D =15A, V _{GS} =15V, R _G =3.3Ω	---	4.6	9.2	ns
t _r	Rise Time		---	12.2	22	ns
t _{d(off)}	Turn-Off Delay Time		---	26.6	53	ns
t _f	Fall Time		---	8	16	ns
Q _g	Total Gate Charge	V _{GS} =4.5V, V _{DS} =15V, I _D =15A	---	17.6	21	nC
Q _{gs}	Gate-Source Charge		---	2.35	5.9	nC
Q _{gd}	Gate-Drain "Miller" Charge		---	5.9	7.1	nC
V _{SD}	Source-Drain Diode Forward Voltage	V _{GS} =0V, I _S =1A	---	---	1	V
I _S	Continuous Source Current	V _G =V _D =0V , Force Current	---	---	58	A
I _{SM}	Pulsed Source Current		---	---	115	A
trr	Reverse Recovery Time	I _F =30A , dI/dt=100A/μs T _J =25°C	---	9.2	---	ns
Qrr	Reverse Recovery Charge		---	2	---	nC

Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.
2. E_{AS} condition: Starting T_J=25°C, V_{DD}=15V, V_G=10V, R_G=25ohm, L=0.5mH, I_{AS}=14A
3. R_{θJA} is measured with the device mounted on a 1inch² pad of 2oz copper FR4 PCB
4. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%.



Typical Characteristics

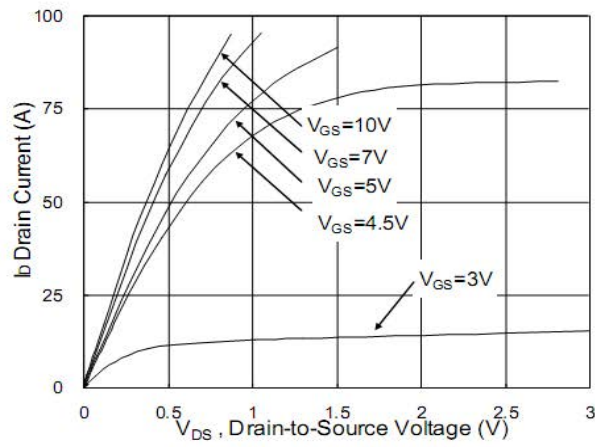


Fig.1 Typical Output Characteristics

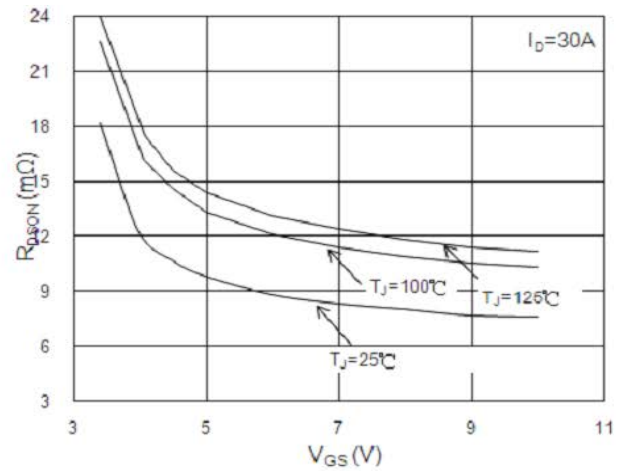


Fig.2 On-Resistance vs. Gate-Source

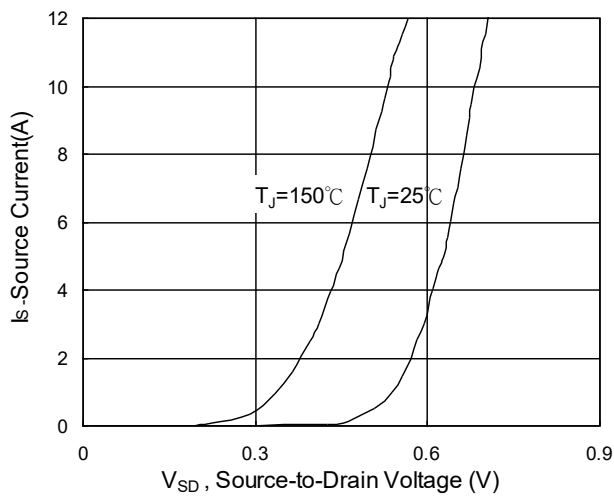


Fig.3 Forward Characteristics of reverse

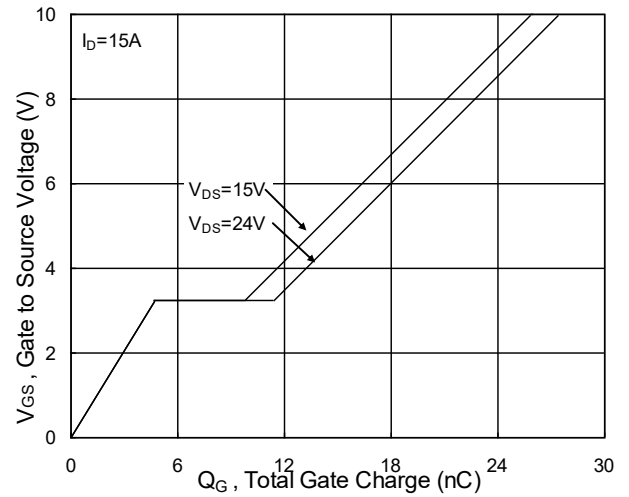


Fig.4 Gate-Charge Characteristics

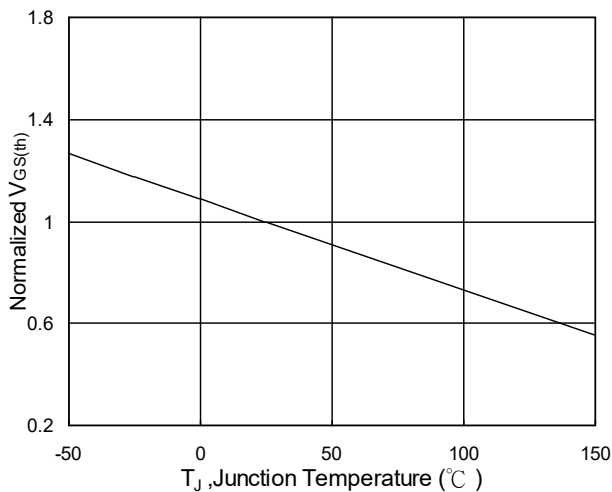


Fig.5 Normalized $V_{GS(th)}$ vs. T_J

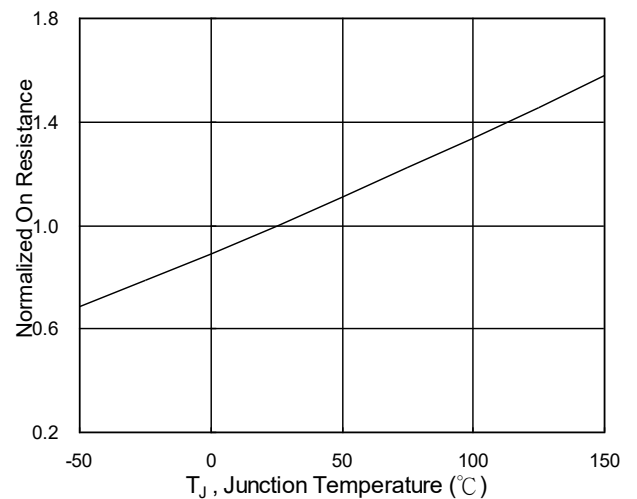


Fig.6 Normalized $R_{DS(on)}$ vs. T_J

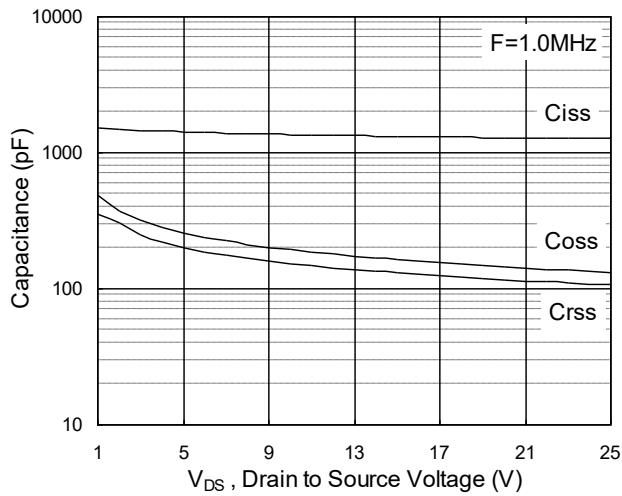


Fig.7 Capacitance

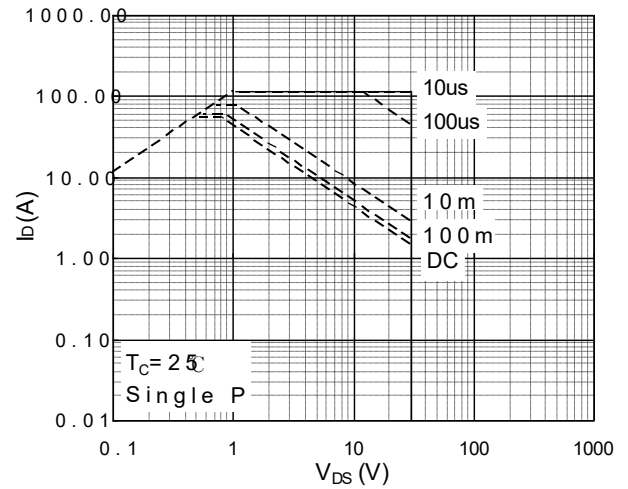


Fig.8 Safe Operating Area

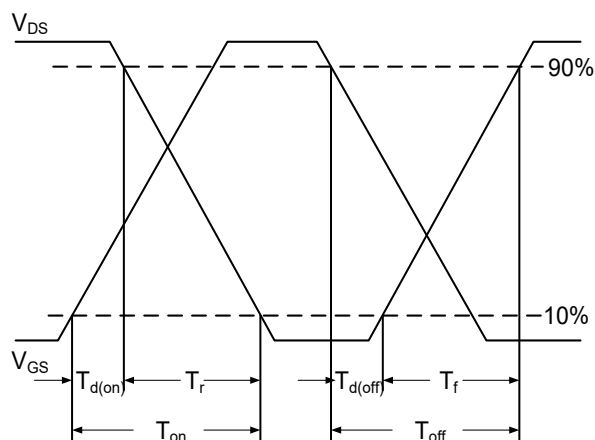


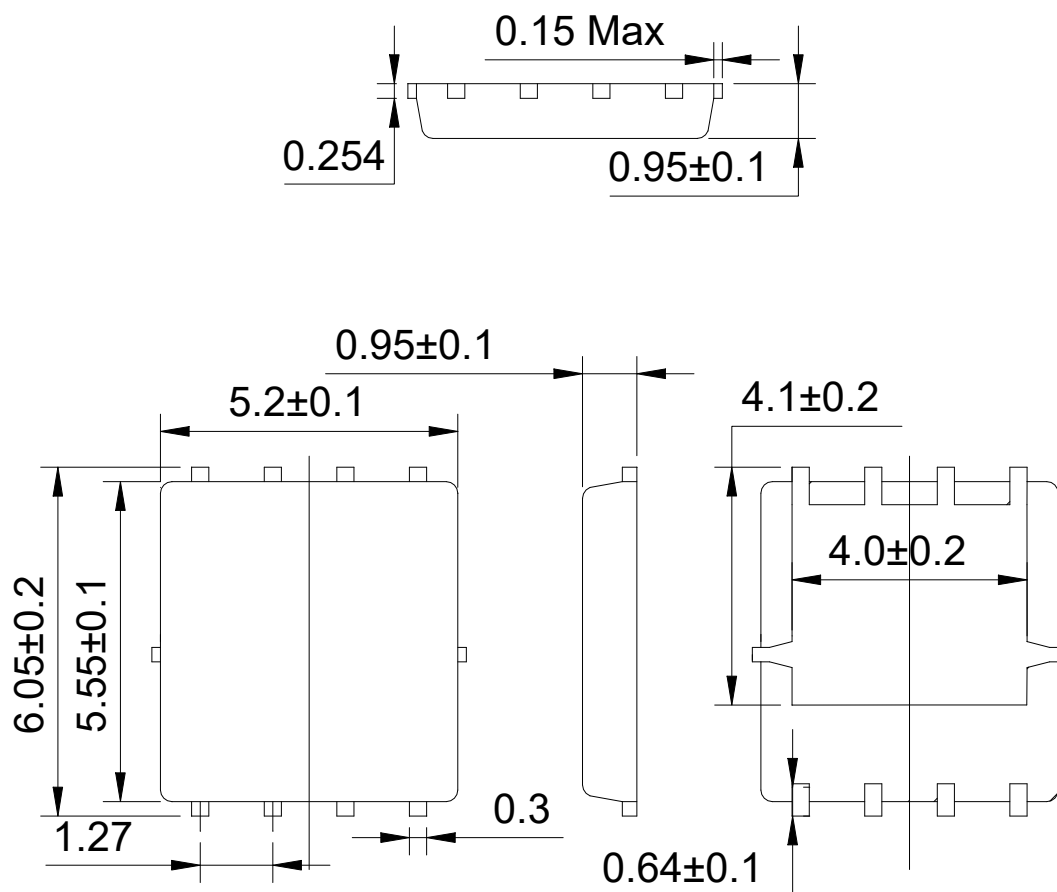
Fig.10 Switching Time Waveform





DFN5X6-8L Package Information

Unit:mm





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